

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring good bidirectional blocking voltage capability and high thermal cycling performance.

2. Features and benefits

- · Good bidirectional blocking voltage capability
- High thermal cycling performance
- Isolated mounting base package
- Planar passivated for voltage ruggedness and reliability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	500	V
I _{T(AV)}	average on-state current	half sine wave; T _h ≤ 69 °C	-	-	7.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; $T_h \le 69 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	12	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	100	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	-	-	110	A
Tj	junction temperature		-	-	125	°C
Static char	acteristics	·		·		
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _i = 25 °C; <u>Fig. 7</u>	-	2	15	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV _D /dt	rate of rise of off-state voltage	$\label{eq:VDM} \begin{array}{l} V_{DM} = 335 \; V; \; T_{j} = 125 \; ^{\circ}\text{C}; \; R_{GK} = 100 \; \Omega; \\ (V_{DM} = 67\% \; of \; V_{DRM}); \; exponential \\ waveform; \; \underline{Fig. \; 12} \end{array}$	200	1000	-	V/µs

5. Pinning information

	. Pinning in		Circulified extiline	Crentia cumbal
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	A - D- K
2	А	anode		G sym037
3	G	gate		- Since
mb	n.c.	mounting base; isolated		
			i ż ś TO-220F (SOT186A)	

6. Ordering information

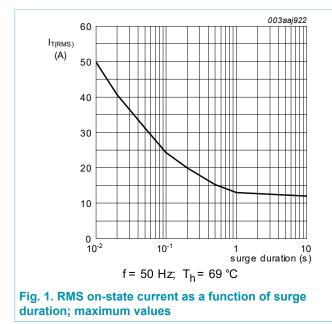
Table 3. Ordering information						
Type number	Package	kage				
	Name	Description	Version			
BT151X-500C	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A			

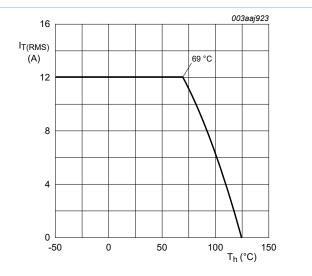
7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	500	V
V _{RRM}	repetitive peak reverse voltage		-	500	V
I _{T(AV)}	average on-state current	half sine wave; T _h ≤ 69 °C	-	7.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_h \le 69$ °C; <u>Fig. 1; Fig. 2;</u> <u>Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	100	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	110	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	50	A²s
dl _T /dt	rate of rise of on-state current	I _G = 30 mA	-	50	A/µs
I _{GM}	peak gate current		-	2	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



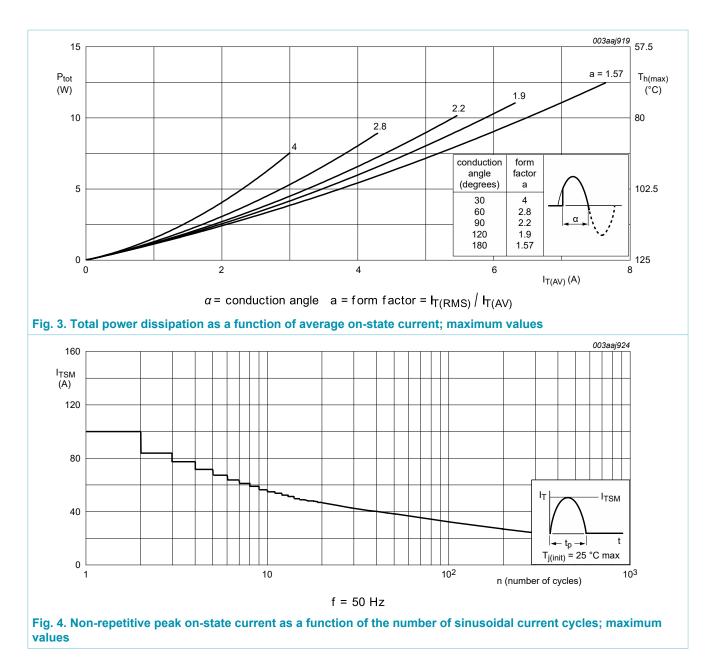




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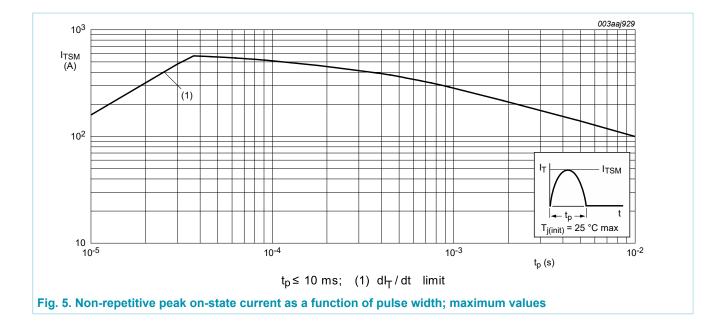


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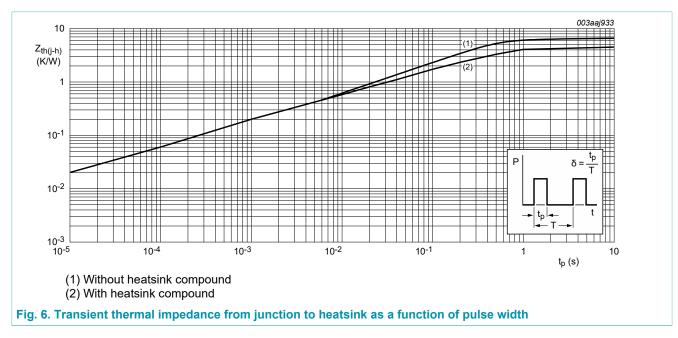
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance	with heatsink compound; Fig. 6	-	-	4.5	K/W
	from junction to heatsink	without heatsink compound; Fig. 6	-	-	6.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



9. Isolation characteristics

Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from anode to external heatsink; f = 1 MHz; T _h = 25 °C	-	10	-	pF

10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · ·				_
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	2	15	mA
۱ _L	latching current	V_D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	0.6	1	V
		V _D = 500 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 500 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 500 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 335 V; T _j = 125 °C; R _{GK} = 100 Ω; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	200	1000	-	V/µs
		V_{DM} = 335 V; T _j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 12	50	130	-	V/µs
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 40 \text{ A}; V_D = 500 \text{V}; \text{I}_G = 100 \text{mA}; \\ \text{d} \text{I}_G/\text{d} \text{t} = 5 \text{A}/\text{\mu}\text{s}; \text{T}_\text{j} = 25 ^\circ\text{C} \end{split}$	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 335 V; T _j = 125 °C; I _{TM} = 20 A; V_R = 25 V; (dI _T /dt) _M = 30 A/µs; dV _D / dt = 50 V/µs; R _{GK(ext)} = 100 Ω; (V _{DM} = 67% of V _{DRM})	-	70	-	μs

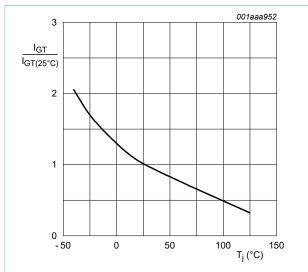


Fig. 7. Normalized gate trigger current as a function of junction temperature

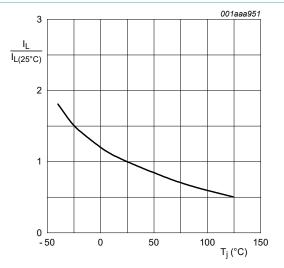
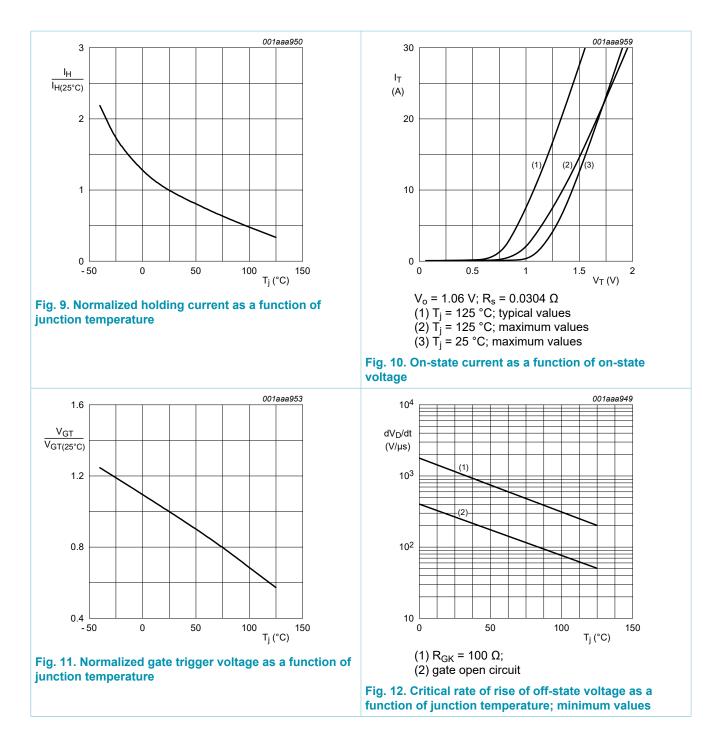


Fig. 8. Normalized latching current as a function of junction temperature

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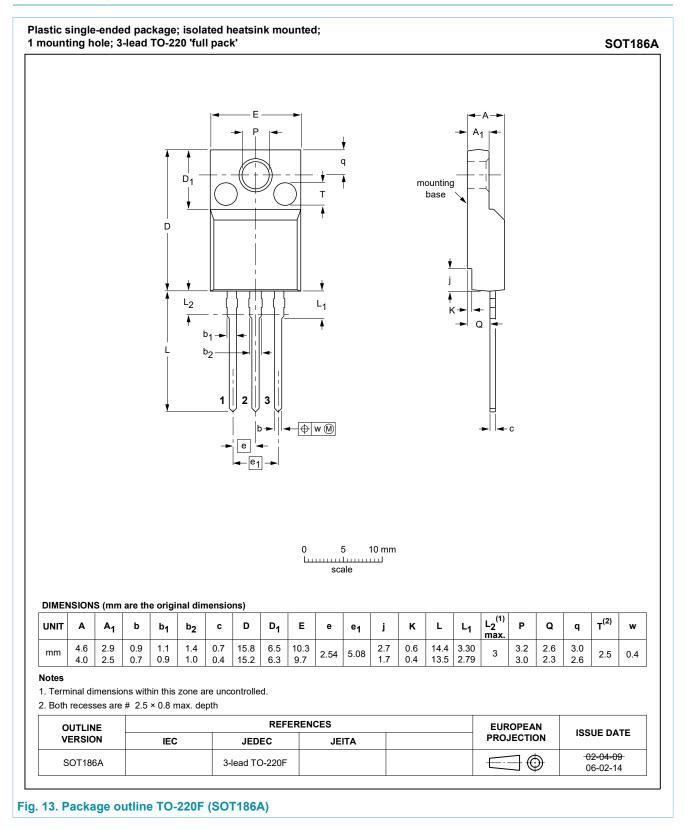
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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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